

MBD5057-E28 Planar Tunnel Diode



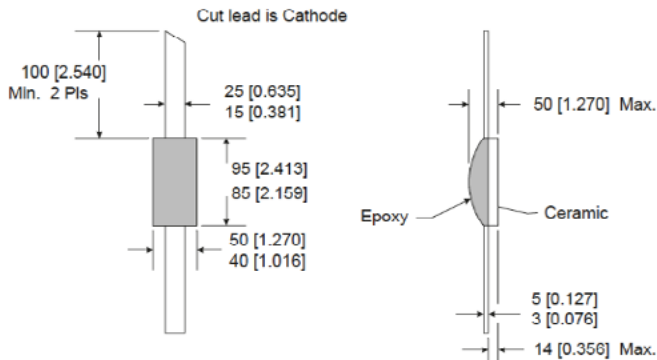
Technical Characteristics

Product Features
Rugged Germanium Planar Construction
Excellent Temperature Stability
No DC Bias Required
Wide Video Bandwidth
MIL-STD-190500 & 883 Qualified

Product Description
EclipseMDI MBD5057-E28, is a zero-bias, rugged Planar Tunnel Diode constructed with Germanium Planar. This tunnel diode exhibits excellent temperature stability, wide video bandwidth and is MIL STD-190500 & MIL-STD-883C qualified. The MBD5057 is also available in hermetic (E28X) ceramic packages.

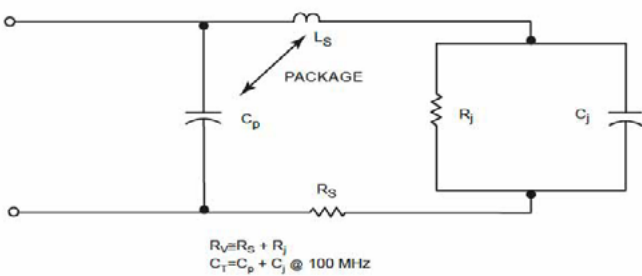
Maximum Ratings
Storage Temperature.....-65° to +125°C
Operating Temperature.....-65° to +110°C
Input Power Handling.....+17dBm CW or 3 ERG spike
Soldering Temperature.....+160° C

E28 Non-Hermetic

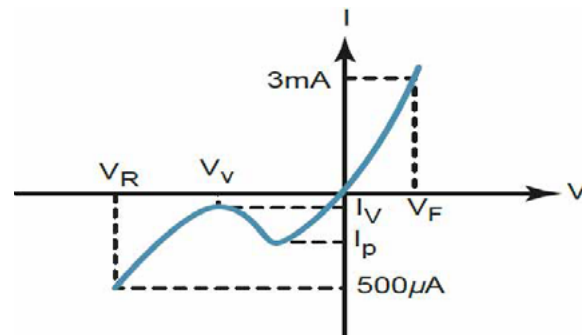


Parameters	Specifications				UNITS
	Conditions	MIN	Typical	MAX	
I _p		500		600	μA
C _j	V _r =V _v , f=100MHz			.30	pF
K[Y]	Pin=-20dBm R _j (Load)=10K, f=10GHz		250		mV/mW
R _v			60		Ω Ohms
I _p /I _v		2.5			
V _r	I _f =500μA		400		mV
V _f	I _f =3mA			110	mV

Diode equivalent circuit



Back diode parameters



About EclipseMDI

ECLIPSE Microdevices is located in San Jose, California. ECLIPSE has been developing high performance analog semiconductors for use in wireless radio frequency (RF), microwave, and millimeter wave for commercial and industrial applications. ECLIPSE has formed a strategic alliances - with foundries that features leading state-of-the-art process technologies and with manufacturing facilities for high-volume production of innovative RFIC's.

Product Export Classification

ECCN: EAR 99 (unless otherwise specified)
HTS: 8542330000